NSN 5961-01-366-2959



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-366-2959 **Inclosure Material:** Metal **Overall Length:** 0.125 inches **Overall Height:** Between 0.017 inches and 0.029 inches **Overall Width:** Between 0.040 inches and 0.052 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Features Provided:** Burn in and gold plated leads **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 800.0 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 microamperes collector current, dc peak **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Terminal Type And Quantity:** 1 ribbon and 1 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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